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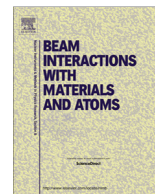
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Derivation of enhanced potentials for cerium brannerite and the calculation of lattice and intrinsic defect properties

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ABSTRACT

A new potential has been derived for ceria and used to calculate its lattice and defect properties. The $\text{Ce}^{4+} \dots \text{O}^{2-}$ potential is obtained via a combination of empirical fitting to crystal structural data and parametric fitting to additional physical properties, while the $\text{O}^{2-} \dots \text{O}^{2-}$ potential is transferred from earlier publications on UO_2 and PuO_2 . The overall potential is subsequently verified and validated by calculation of elastic and dielectric constants, whose values agree favourably with those measured experimentally. The potential is then employed to calculate intrinsic defect formation energies and predict the most favourable type of intrinsic disorder.

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1. Introduction

High Level Waste (HLW), containing up to 95% of the radioactivity associated with a nuclear power station [1], comprises energetic fission products many of which have long half-lives and must therefore be isolated from the biosphere [2]. Borosilicate glass is currently the most commonly employed immobilizing matrix. However, the limited solubility of some HLW components and suggestions of inhomogeneity of the borosilicate matrix, has led to active research of ceramics, particularly those with mineral analogues, as alternative host matrices [3].

The mineral brannerite, UTi_2O_6 , has a high actinide content and is extremely durable despite a wide variety of chemical substitution on both cation sites [4]. Synthetically, brannerite is a significant minor phase in pyrochlore-zirconolite ceramics designed for HLW immobilization [5]. It is therefore important to consider the applicability of brannerite as an actinide immobilizing matrix. Cerium is often used as an actinide simulant [6], particularly for plutonium, and CeTi_2O_6 is iso-structural with both UTi_2O_6 and PuTi_2O_6 [7].

Included in the detailed study of the structural properties of CeTi_2O_6 by Stennett et al. [7], are atomistic simulations employing potentials from the library of Woodley et al. [8]. However, the reported results were not reproducible with the listed potentials. Moreover, the interatomic potential employed for the anion inter-

actions includes an attractive r^{-6} term that causes unphysical and catastrophic attraction when the anions are separated by less than 1.85 Å. In addition, as seen when other potentials from the same library were used in the simulation of κ -alumina [9], these potentials give rise to further anomalies.

In this study, methods similar to those adopted previously for UO_2 [10] are applied to CeO_2 in order to obtain information about lattice properties and defect behaviour. This is an important preliminary step in modelling cerium brannerite which is the subject of ongoing work and a future publication.

2. Computational methodology

The computational methods used in this work are established techniques that have been used in many applications [11,12]. The pairwise interactions in the material are defined by a linear sum of an electrostatic interaction term and an interatomic potential (Eq. (1)):

$$V_{ij} = A_{ij} \underbrace{\exp\left(-\frac{r_{ij}}{\rho_{ij}}\right)}_{\text{Buckingham}} - \underbrace{\frac{C_{ij}}{r_{ij}^6} + \frac{q_i q_j}{r_{ij}}}_{\text{Electrostatic}} \quad (1)$$

For the interatomic potential term, the Buckingham form is employed in which q_i and q_j are the formal charges on the ions and the parameters A , ρ and C are specified, through empirical fitting, for each interaction type. Ion polarization by highly charged

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ions and defects is incorporated using Dick and Overhausers shell model [13] and intrinsic defects are modelled with the computationally efficient Mott Littleton [14] procedure.

2.1. Anion – anion potential

The interactions between the anions are described using a Buckingham four range potential: this was reported for UO₂ [10,15] and has subsequently been used in simulations of SiO₂ [16], PuO₂ [17] and ThO₂ [18]. Its use here is reasonable as CeO₂ adopts the same cubic crystal structure, with the anions arranged with the same symmetry within unit cells of a similar size. The potential is defined by the intervals given in Eq. (2) such that only the relevant terms of the Buckingham function are used over specific interaction distances. At the points cut₁, r_{minimum} and cut₂, the functions are splined such that their first and second derivatives are continuous. Furthermore, the function is constrained to have a minimum stationary point at r_{min}. Values for the necessary parameters, are reported by Jackson et al. and the constants for the polynomials calculated using the spline fitting procedure embodied within the GULP [19] code.

$$\phi^{\text{Buck4}}(r_{ij}) = \begin{cases} A_{ij} \exp\left(-\frac{r_{ij}}{\rho_{ij}}\right) & \text{if } r_{\min} < r_{ij} \leq \text{cut}_1, \\ \sum_{m=0}^5 a_m r_{ij}^m & \text{if } \text{cut}_1 < r_{ij} \leq r_{\text{minimum}}, \\ \sum_{n=0}^3 b_n r_{ij}^n & \text{if } r_{\text{minimum}} < r_{ij} \leq \text{cut}_2, \\ -\frac{C_{ij}}{r_{ij}^6} & \text{if } \text{cut}_2 < r_{ij} \leq r_{\max} \end{cases} \quad (2)$$

2.2. Cation – anion potential

Owing to the absence of a stationary point in the function of the cation–anion interactions, the Buckingham four range potential form is thus not applicable. To the best of the authors knowledge, there exists no standard Buckingham form potentials for Ce⁴⁺ ... O²⁻ interactions that are consistent with the Buckingham four range potential detailed above. Thus, this is derived, with the C parameter set to zero in order to overcome the unphysical phenomenon of catastrophic attractions when ions are in close proximity: the potentials are thus formally of the Born Mayer form. The nature of the excluded (−C/r⁶) term is incorporated by surveying the potential landscape and sequentially selecting A and ρ parameters using an empirical fitting procedure which requires no *a priori* assumption of starting values and has been used to derive potentials for use in simulations of UO₂ [10], PuO₂ [17] and ThO₂ [18].

Initially, a range of A (650–2000 eV) and ρ (0.30–0.45 Å) values is screened and the difference between the experimentally observed and predicted lattice constant plotted in Fig. 1.

Interpolation of the surface for where this difference is zero provides a solution set (Fig. 2) of several pairs of A and ρ that accurately reproduce the crystal structure.

For a robust model, however, the physical characteristics of the lattice should be described. Therefore, the predicted elastic constants are plotted as a function of the A parameter of corresponding pairs in the solution set (Fig. 3 and a value of A selected where the mean percentage difference between the predicted and observed values (overlaid in Fig. 3) of the elastic constants is a minimum. The corresponding ρ value is obtained through interpolation of the solution set.

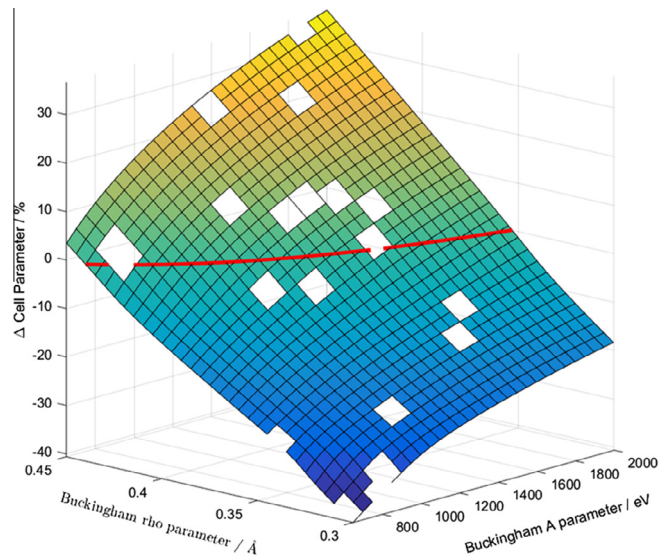


Fig. 1. Plot of the difference between predicted and observed CeO₂ lattice constant for A and ρ values of the Ce⁴⁺ ... O²⁻ Born–Mayer potential.

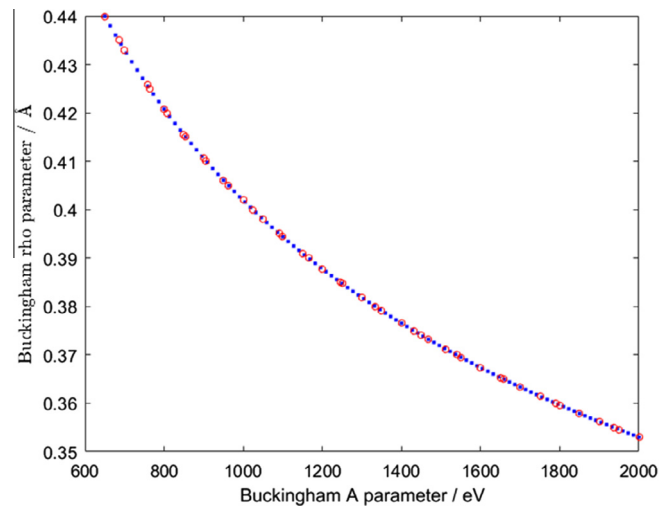


Fig. 2. Zero contour points and interpolated values of A and ρ comprising the solution set.

3. Results and discussion

3.1. Experimental data

CeO₂ adopts the fluorite structure (*Fm* $\bar{3}$ *m*) and is isomorphous with UO₂, PuO₂ and ThO₂. The face centred cubic lattice has a lattice constant, a₀, of 5.4112 Å [20] and a basis of a cerium ion at the origin and oxygen ions at $\pm(\frac{1}{4}, \frac{1}{4}, \frac{1}{4})$: the anions form a simple cubic sub-lattice. There are 4 cations and 8 anions per unit cell. The fitting procedure also employs the elastic constants (C₁₁, C₁₂ and C₄₄), static and high frequency dielectric constants and these are summarised, along with other bulk properties to be used for validating the simulation, in Table 2.

3.2. Perfect lattice

Values for the parameters of the Ce⁴⁺ ... O²⁻ potential derived in the previous section and the Buckingham four range O²⁻ ... O²⁻ potential are given in Table 1.

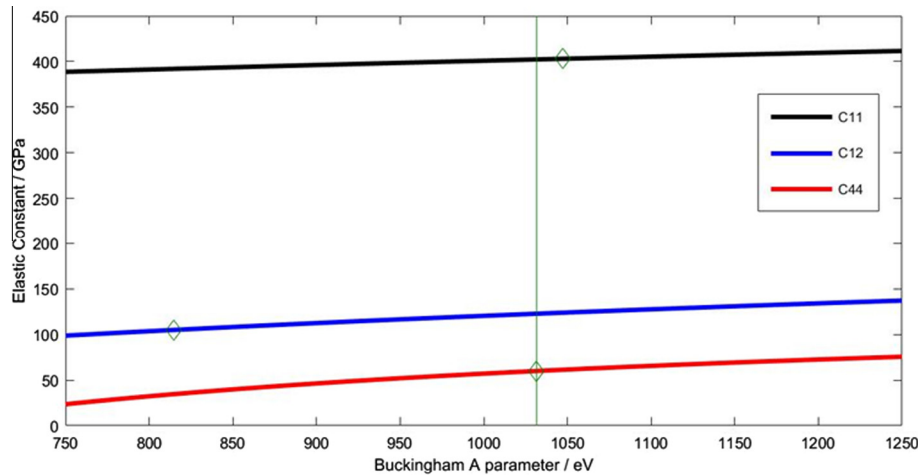


Fig. 3. Plot of predicted and observed elastic constants as a function of A .

Table 1
Lattice potentials for CeO_2 .

Interaction	Short-range parameters			Shell model [*]	
	A eV	ρ Å	C eV Å ⁶	Y e	k_2 eV Å ⁻²
$\text{Ce}^{4+} \dots \text{O}^{2-}$	1031.57	0.399447	0.0	-2.54	105.358
$\text{O}^{2-} \dots \text{O}^{2-(a)}$	11272.6	0.1363	134.0	-4.4	296.2
	r_{\min} Å	cut_1 Å	r_{minimum} Å	cut_2 Å	r_{\max} Å
	0.0	1.2	2.1	2.6	15.0

^{*} Y and k_2 are the shell charge and spring constant respectively

^(a) Reference [15]

The validity of the potentials used and the applicability of the model is assessed by comparing the predicted values of perfect lattice properties with those that have been experimentally observed. Table 2 shows excellent agreement between calculated parameters and reported crystallographic data, elastic constants and both static and high frequency dielectric constants. However, such good agreement is not surprising as these properties were used in the potential derivation: further validation of the model is thus carried out through consideration of additional properties listed in Table 2, with prediction once again being compared with reported observation. Comparison with potentials [8,21–26] taken from the literature shows the parameterisation used in this work to be an improved fit.

3.3. Intrinsic defects

Calculations were performed initially on the energies of isolated point defects: results are given in Table 3. In all cases, the lattice ions surrounding the defect are allowed to relax in the energy minimisation procedure using the Mott-Littleton procedure [14], in which the immediate surroundings of the defect are treated explicitly and approximations used for more distant regions: consistent region sizes of 14 Å and 28 Å were used, giving ≈ 1800 ions in region 1 and $\approx 12,300$ ions in region 2.

Frenkel and Schottky disorder formation energies are predicted by combining individual point defect energies. However, this assumes the defects are at infinite dilution and does not take into account the binding energy associated with defect aggregation. This is addressed by performing cluster calculations: the binding energies are then determined as the difference in energy between the cluster and its constituent point defects at infinite dilution.

3.3.1. Frenkel pair clusters

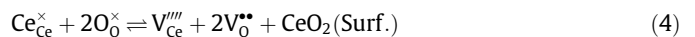
Using Kröger Vink notation [35] notation, Frenkel defects can be represented as:



For the oxygen Frenkel cluster simulations, the interstitial and vacancy are separated by a cerium ion in order to prevent the recombination seen when the defects are in close proximity. Two geometries for the oxygen Frenkel Pair are considered and the respective coordinates and resulting energies listed in Table 4.

3.3.2. Schottky defect clusters

Using Kröger Vink notation, Schottky defects are represented as:



In a similar manner to that used for the oxygen Frenkel pairs, three configurations of the trio of vacancies in Schottky disorder were simulated. In all three configurations, the cerium vacancy is positioned at (0,0,0) and the first oxygen vacancy positioned at (0,0,0). The coordinates of the second oxygen vacancy, which preserves charge neutrality, and the associated energies are given in Table 5. The most energetically favourable position for the second oxygen vacancy is predicted to be that of the Sch. 2 configuration and this cluster energy is combined with the associated energy of forming CeO_2 at the surface to predict the Schottky defect energy detailed in Table 6.

Formation energies for Frenkel and Schottky disorder, found from both combining point defect energies and cluster calculations, are given in Table 6. It can be seen that for all defect types

Table 2Comparison of predicted and observed properties of CeO₂.

Property	Observed	This work		Butler [21]		Gotte [22]		Woodley [8]		Minervini [23]		Vyas [24]		Li [25]		Ghosh* [26]	
			Δ %		Δ %		Δ %		Δ %		Δ %		Δ %		Δ %		Δ %
Lattice Constant: (a_0) (Å)	5.4112	5.4114	0.004	5.4677	1.044	5.4070	−0.078	5.4110	−0.004	5.4100	−0.022	5.4110	−0.004	5.4080	−0.059	5.3960	−0.281
Elastic Constants:																	
C ₁₁ (GPa)	403 ^(b)	402.3	−0.17	490.2	21.64	405.5	0.62	587.8	45.86	554.5	37.59	573	42.18	503.7	24.99	410.5	1.86
C ₁₂ (GPa)	105 ^(b)	122.8	16.95	140.6	33.90	104.3	−0.67	111.3	6.00	124.6	18.67	147.7	40.67	143.9	37.05	79.2	−24.57
C ₄₄ (GPa)	60.0 ^(b)	60	0.00	132.4	120.67	60.6	1.00	61.6	2.67	123.1	105.17	146.8	144.67	143.7	139.50	78.5	30.83
Moduli:																	
Bulk (GPa)	204 – 240 ^(c)	215.96		257.13		204.71		270.15		267.92		289.42		263.83		189.61	
Shear (GPa)	96 – 149 ^(d)	91.9		149.37		96.58		132.26		159.85		173.12		158.17		113.35	
Young's (GPa)	249 ^(b)	344.86		427.52		362.79		552.34		508.78		512.45		439.68		384.94	
Dielectric Constants:																	
Static ϵ_0	23 – 35.3 ^(e)	26.73		22.52		18.721		11.26		18.62		12.71		10.41		4.615	
High Frequency ϵ_∞	4.7 – 6.0 ^(e)	5.518		5.415		4.012		4.23		5.88		3.98		1.09			

(a) Reference [20], (b) Reference [27], (c) Reference [28–31], (d) Reference [27,28], (e) Reference [32,33,34], * Partial charge model.

Table 3Defect formation energies for isolated defects in CeO₂

Defect	Position	Formation Energy/ eV
Ce ⁴⁺ Vacancy ($V_{\text{Ce}}^{\text{IV}}$)	(0,0,0)	78.60
O ^{2−} Vacancy (V_{O}^{II})	($\frac{1}{4}, \frac{1}{4}, \frac{1}{4}$)	16.37
Ce ⁴⁺ Interstitial (Ce_i^{IV})	($\frac{1}{2}, \frac{1}{2}, \frac{1}{2}$)	−61.66
O ^{2−} Interstitial (O_i^{II})	($\frac{1}{2}, \frac{1}{2}, \frac{1}{2}$)	−11.87

Region I contains 1800 ions.

Table 4

Formation and binding energies of the considered configurations for the oxygen Frenkel pair defect.

Type of defect	V_{O}^{II} Position	O_i^{II} Position	Formation energy (eV/Defect)	Binding energy (eV/Defect)
OPF 1	($-\frac{1}{4}, -\frac{1}{4}, -\frac{1}{4}$)	($\frac{1}{2}, \frac{1}{2}, \frac{1}{2}$)	1.55	−0.70
OPF 2	($-\frac{1}{4}, -\frac{1}{4}, \frac{1}{4}$)	($\frac{1}{2}, \frac{1}{2}, \frac{1}{2}$)	1.86	−0.40

there is a net binding energy. It is also interesting to note that consideration of only defects at infinite dilution would lead to the conclusion that oxygen Frenkel disorder, having the lowest formation energy and thus being the most thermodynamically stable, would dominate. When defect aggregation is taken into account, however, the Schottky trio of vacancies is predicted to have the lowest formation energy. Thus, cerium and oxygen vacancies are expected in the structure in accord with observation.

4. Conclusions and future work

A potential has been fitted to the structure and properties of CeO₂ using a robust procedure to ensure the crystallographic and mechanical properties are reproduced accurately. Starting from a solution set of parameters which correctly reproduce the crystallographic structure, values are selected based on their ability to reproduce the elastic and dielectric constants of the lattice. The derived potential is then validated by calculating additional bulk properties not used in the derivation procedure.

Subsequent to the derivation and validation of the potential using the pure lattice, calculated energies of intrinsic point and cluster defects are used to predict Frenkel and Schottky energies:

Table 5Formation and binding energies of the Ce⁴⁺ and 2 O^{2−} vacancy clusters.

Type of defect	Second V_{O}^{II} Position (eV/Defect)	Formation energy	Binding Energy (eV/Defect)
Sch. 1	($-\frac{1}{4}, -\frac{1}{4}, -\frac{1}{4}$)	35.95	−1.17
Sch. 2	($-\frac{1}{4}, \frac{1}{4}, -\frac{1}{4}$)	35.92	−1.19
Sch. 3	($-\frac{1}{4}, \frac{1}{4}, \frac{1}{4}$)	36.12	−0.99

Table 6Calculated formation and binding energies of the ionic defects in CeO₂.

Type of defect	Defect formation energy		Binding Energy (eV/Defect)
	Unbound (eV/Defect)	Bound (eV/Defect)	
Ce Frenkel	8.47	6.71	−1.77
O Frenkel	2.25	1.86	−0.40
Schottky Trio	2.78	1.59	−1.19

Schottky defects are found to be the most energetically favourable form of intrinsic defect. The potential derived in this work will now be used in the atomistic simulation of cerium brannerite, CeTi₂O₆.

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